

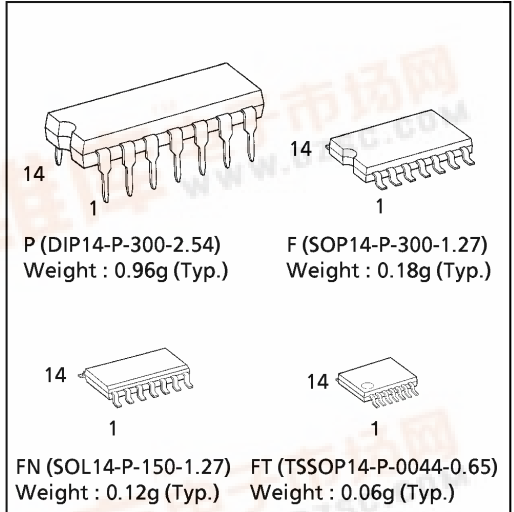
TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC4001BP, TC4001BF, TC4001BFN, TC4001BFT

TC4001B QUAD 2 INPUT NOR GATE

The TC4001B is 2-input positive NOR gate, respectively. Since the outputs of these gates are equipped with the buffers, the input/output transmission characteristics have been improved and the variation of transmission time due to an increase in the load capacity is kept minimum.

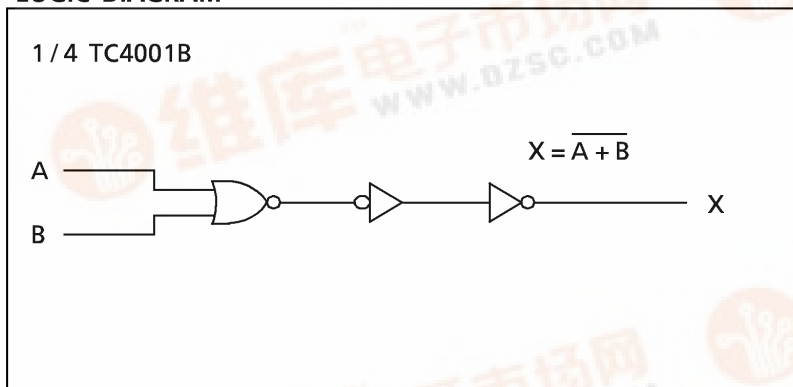
(Note) The JEDEC SOP (FN) is not available in Japan.



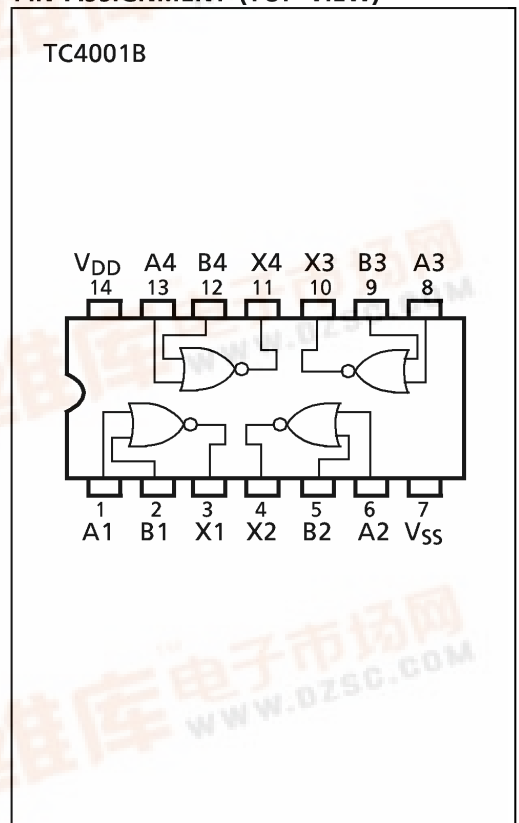
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V _{DD}	V _{SS} - 0.5 ~ V _{SS} + 20	V
Input Voltage	V _{IN}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
Output Voltage	V _{OUT}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
DC Input Current	I _{IN}	± 10	mA
Power Dissipation	P _D	300 (DIP) / 180 (SOIC)	mW
Operating Temperature Range	T _{opr}	- 40 ~ 85	°C
Storage Temperature Range	T _{stg}	- 65 ~ 150	°C

LOGIC DIAGRAM



PIN ASSIGNMENT (TOP VIEW)



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● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.



RECOMMENDED OPERATING CONDITIONS (V_{SS} = 0V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	V _{DD}		3	—	18	V
Input Voltage	V _{IN}		0	—	V _{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS} = 0V)

CHARACTERISTIC	SYM-BOL	TEST CONDITION	V _{DD} (V)	-40°C		25°C			85°C		UNIT	
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Output Voltage	V _{OH}	I _{OUT} < 1μA V _{IN} = V _{SS} , V _{DD}	5	4.95	—	4.95	5.00	—	4.95	—	V	
			10	9.95	—	9.95	10.00	—	9.95	—		
			15	14.95	—	14.95	15.00	—	14.95	—		
Low-Level Output Voltage	V _{OL}	I _{OUT} < 1μA V _{IN} = V _{SS} , V _{DD}	5	—	0.05	—	0.00	0.05	—	0.05	V	
			10	—	0.05	—	0.00	0.05	—	0.05		
			15	—	0.05	—	0.00	0.05	—	0.05		
Output High Current	I _{OH}	V _{OH} = 4.6V V _{OH} = 2.5V V _{OH} = 9.5V V _{OH} = 13.5V V _{IN} = V _{SS}	5	-0.61	—	-0.51	-1.0	—	-0.42	—	mA	
			5	-2.50	—	-2.10	-4.0	—	-1.70	—		
			10	-1.50	—	-1.30	-2.2	—	-1.10	—		
			15	-4.00	—	-3.40	-9.0	—	-2.80	—		
Output Low Current	I _{OL}	V _{OL} = 0.4V V _{OL} = 0.5V V _{OL} = 1.5V V _{IN} = V _{SS} , V _{DD}	5	0.61	—	0.51	1.2	—	0.42	—	mA	
			10	1.50	—	1.30	3.2	—	1.10	—		
			15	4.00	—	3.40	12.0	—	2.80	—		
			5	3.5	—	3.5	2.75	—	3.5	—		
Input High Voltage	V _{IH}	V _{OUT} = 0.5V V _{OUT} = 1.0V V _{OUT} = 1.5V I _{OUT} < 1μA	10	7.0	—	7.0	5.50	—	7.0	—	V	
			15	11.0	—	11.0	8.25	—	11.0	—		
			5	—	1.5	—	2.25	1.5	—	1.5		—
Input Low Voltage	V _{IL}	V _{OUT} = 4.5V V _{OUT} = 9.0V V _{OUT} = 13.5V I _{OUT} < 1μA	10	—	3.0	—	4.50	3.0	—	3.0	V	
			15	—	4.0	—	6.75	4.0	—	4.0		
			5	—	1.5	—	2.25	1.5	—	1.5		—
Input Current	"H" Level	I _{IH}	V _{IH} = 18V	18	—	0.1	—	10 ⁻⁵	0.1	—	1.0	μA
	"L" Level	I _{IL}	V _{IL} = 0V	18	—	-0.1	—	-10 ⁻⁵	-0.1	—	-1.0	
Quiescent Supply Current	I _{DD}	V _{IN} = V _{SS} , V _{DD} *	5	—	0.25	—	0.001	0.25	—	7.5	μA	
			10	—	0.50	—	0.001	0.50	—	15.0		
			15	—	1.00	—	0.002	1.00	—	30.0		

* All valid input combinations.

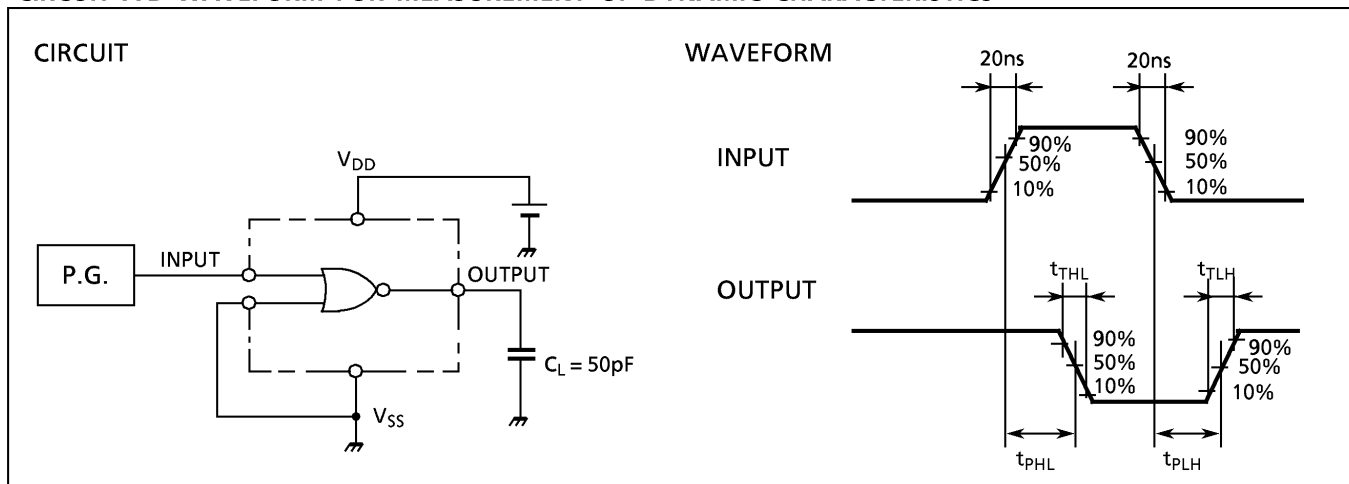
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DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C, Vss = 0V, CL = 50pF)

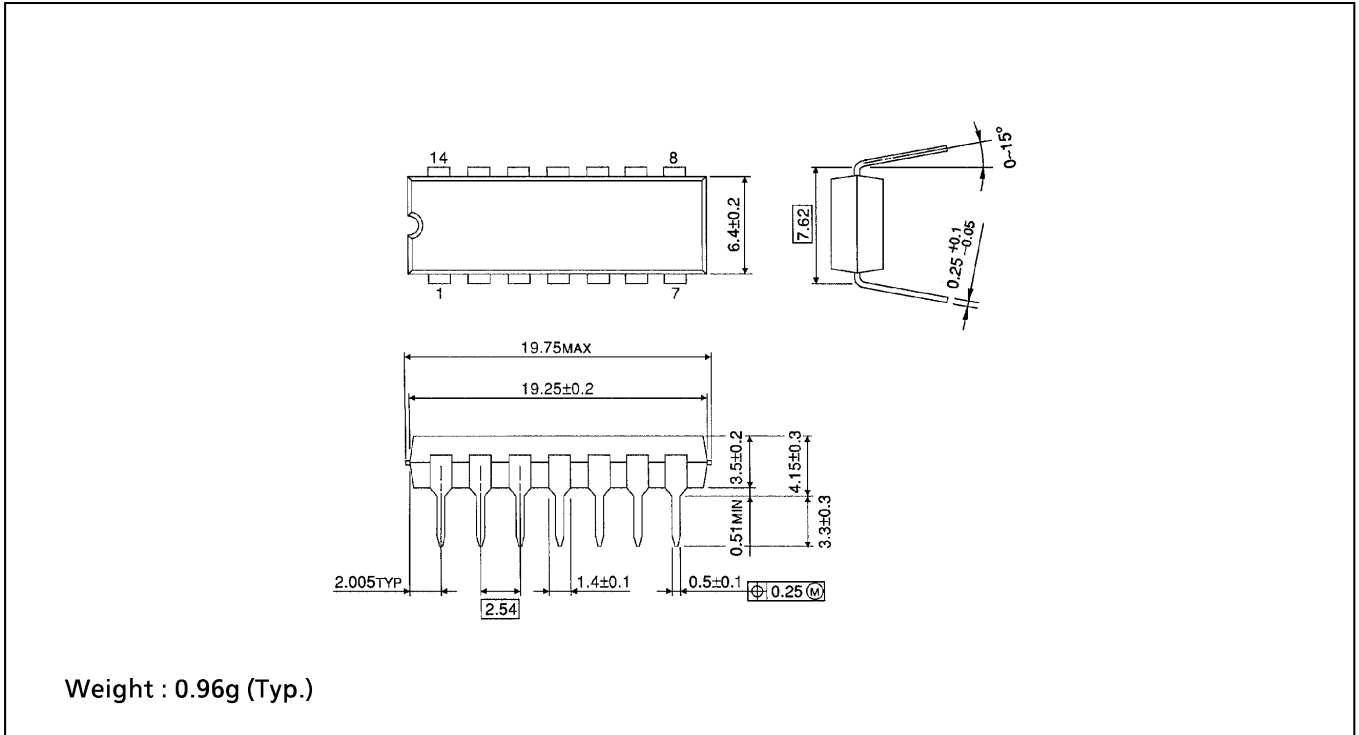
CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{DD} (V)	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t _{TLH}		5	—	70	200	ns
			10	—	35	100	
			15	—	30	80	
Output Transition Time	t _{THL}		5	—	70	200	
			10	—	35	100	
			15	—	30	80	
Propagation Delay Time	t _{pLH}		5	—	65	200	
			10	—	30	100	
			15	—	25	80	
Propagation Delay Time	t _{pHL}		5	—	65	200	
			10	—	30	100	
			15	—	25	80	
Input Capacitance	C _{IN}			—	5	7.5	pF

CIRCUIT A D WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS



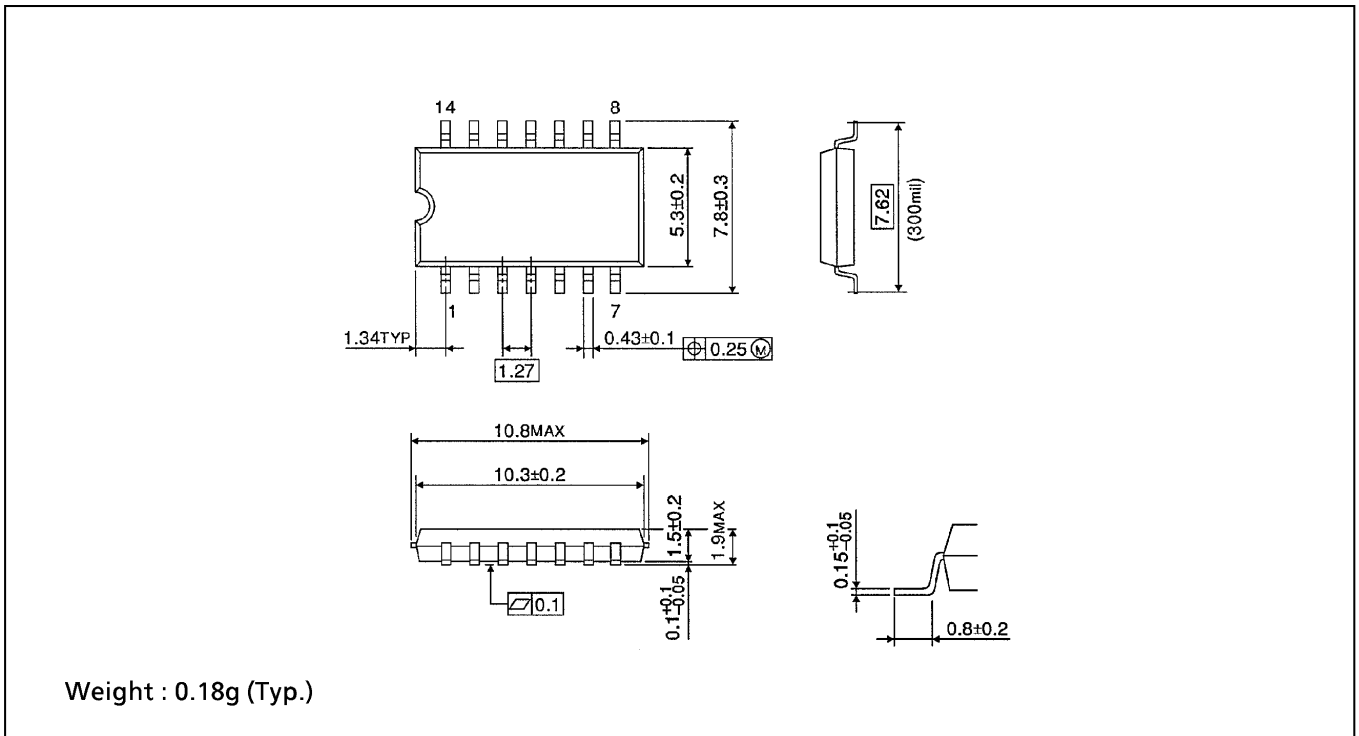
DIP 14PIN OUTLINE DRAWING (DIP14-P-300-2.54)

Unit in mm



SOP 14PIN (200mil BODY) OUTLINE DRAWING (SOP14-P-300-1.27)

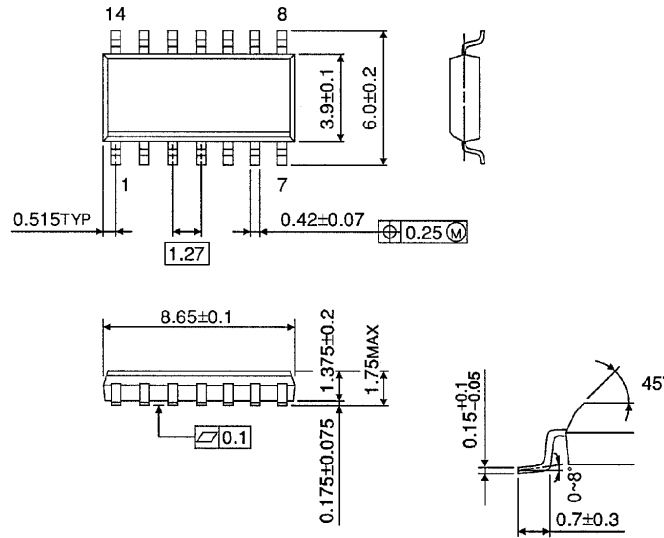
Unit in mm



SOP 14PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150 -1.27)

Unit in mm

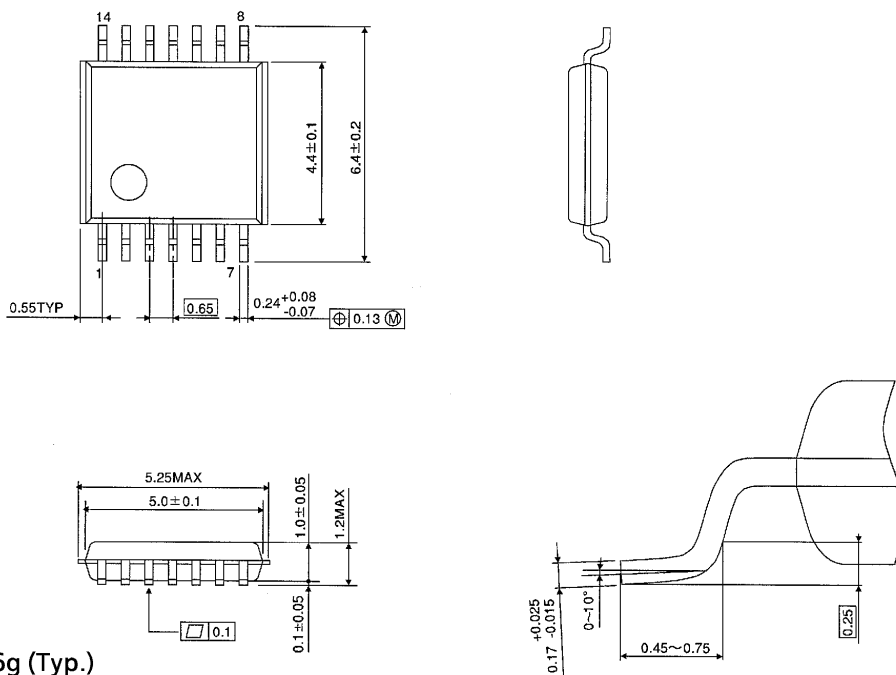
(Note) This package is not available in Japan.



Weight : 0.12g (Typ.)

TSSOP 14PIN (170mil BODY) OUTLINE DRAWING (TSSOP14-P-0044-0.65)

Unit in mm



Weight : 0.06g (Typ.)